

Industrial MLC NAND

SD CARD

SDI330 SERIES

microSD CARD

SDT330 SERIES

SD 3.0 UHS-I

3K PE Cycles MLC NAND



PRODUCT FEATURES

- MLC Flash Technology with 3K PE cycles endurance
- Global Wear Leveling, Static & Dynamic Wear Leveling and Early weak block retirement
- Sudden Power-Off Recovery (SPOR) resilient firmware with capability to avoid firmware crash when sudden power loss or unstable voltage occurs during operation mode and device initialization stage.
- Auto Read-Refresh, Read retry, Garbage collection
- SP Toolbox utility program to monitor Overall health status, Power Cycle count, Abnormal power cycle count,
- Bad block status including initial bad blocks, later bad blocks and spare blocks, Erase counts, ECC Uncorrectable counts.
- SP SMART Embedded applications with seamless integration with an edge's device operating system.
- SP SMART IoT Sphere providing cloud service with alarm and notifications which monitors and analyzes the health and status of SP Flash products inside the connected devices.

PRODUCT SUMMARY

Capacities: 8GB, 16GB, 32GB, 64GBForm Factor: SD Card, microSD Card

Compliance : SD Specification: SD 3.0 UHS-I

Speed Class: Class 10, U1

Performance :

	8GB	16GB	32GB	64GB	
Sequential Read (MB/s Max.)	85	85	85	85	
Sequential Write (MB/s Max.)	20	30	30	30	

^{*} Actual performance may vary based on the specific model and capacity

Operating Temperature Range:

Normal: -25 °C to 85 °C Wide: -40 °C to 85 °C

Storage Temperature Range: -40 °C to 85 °C

Operating Voltage: 3.3 V ± 10%

Power Consumption (Maximum, unit: mA)

Read: 400mA Write: 400mA Stand-by: 1mA

Data Retention @40 °C: 10 Years @ Life Begin; 1 Year @ Life End

• Endurance in Tera Bytes Written (TBW) : (Unit: TB)

Workload	8GB	16GB	32GB	64GB	
TBW	9.6	19.2	38.4	76.8	

Mechanical (SDA Spec) :

Bare Drop: 150cm free fall 6 faces

Torque: 0.15N Bending: 10N-m

- BCH ECC up to 43 bits/1KB to ensure reliable 3K PE cycles with MLC Flash
- Mean Time Between Failure: > =2,000,000 hours
- Serious quality control and assurance

100% NAND Flash screening

Duration: 10,000 cycles

Compliant with SDA Spec. ISO 7816-1 to pass UV light exposure and X-ray exposure

Reliability criteria compliant with international standards IEC-60068 (Environmental test) and IEC-61000-4-2 (ESD, Contact +/-4KV, Air discharge +/-8KV)



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